



Product Summary

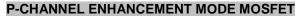
BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	100mΩ @ V _{GS} = -4.5V	-2.0A
-20V	120mΩ @ V _{GS} = -2.5V	-1.9A
	160mΩ @ V _{GS} = -1.8V	-1.6A

Description

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Motor Control
- Power Management Functions
- Backlighting



Features and Benefits

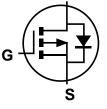
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

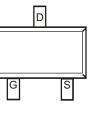
Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish—Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.006 grams (Approximate)



Top View





Top View

Internal Schematic

Ordering Information (Note 4)

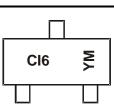
	Part Number	Case	Packaging				
	DMP2110UW-7	SOT323	3000/Tape & Reel				
DMP2110UW-13		SOT323	10,000/Tape & Reel				
Notes:	s: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.						

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



CI6 = Marking Code YM = Date Code Marking \overline{Y} = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	2018		2019	2020		2021	2022		2023	2024		2025
Code	F		G	Н		I	J		K	L		Μ
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	-20	V	
Gate-Source Voltage		V _{GSS}	±12	V	
Continuous Drain Current (Note 6) $V_{GS} = -4.5V$ State $T_A = +25$ State $T_A = +70$			ID	-2.0 -1.6	А
Maximum Continuous Body Diode Forward Currer	nt (Note 6)	Is	-0.9	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%) (Note 6	I _{DM}	-15	А	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	0.49	mW
Thermal Resistance, Junction to Ambient	$R_{ heta}$ JA	253	°C/W
Total Power Dissipation (Note 6)	PD	0.65	mW
Thermal Resistance, Junction to Ambient	R _{0JA}	192	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

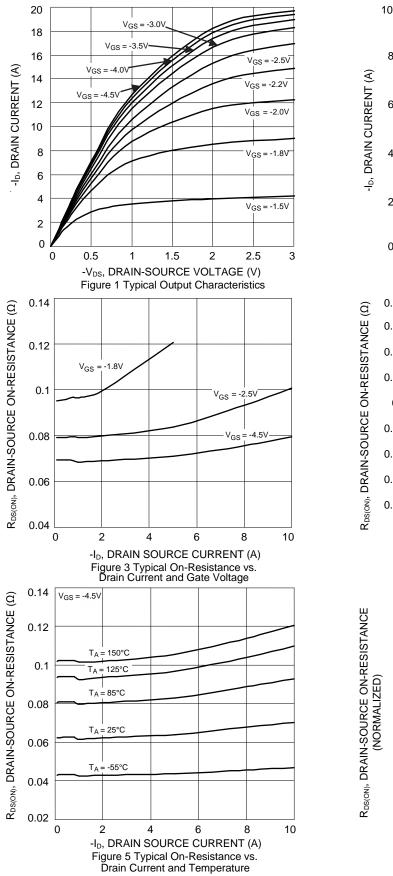
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

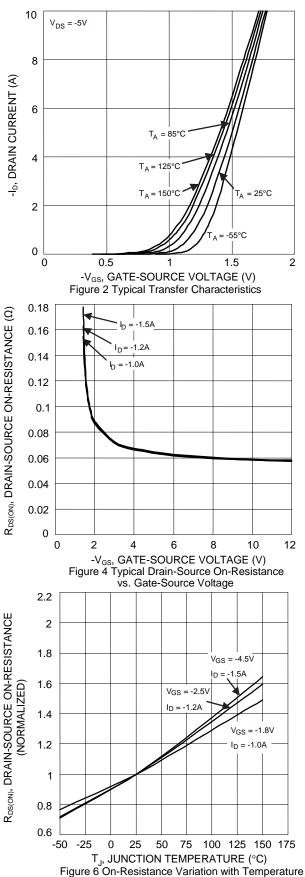
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)		•		•			
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}	_	—	-1.0	μA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
	IGSS	—	—	±800		$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-0.4	_	-0.9	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
			63	100		$V_{GS} = -4.5V, I_D = -1.5A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	—	75	120	mΩ	$V_{GS} = -2.5V, I_D = -1.2A$	
			89	160		$V_{GS} = -1.8V, I_D = -1A$	
Diode Forward Voltage	V _{SD}	—	-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -1.0A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	443	—	pF		
Output Capacitance	Coss	—	59	—	pF	V _{DS} = -6V, V _{GS} = 0V f = 1.0MHz	
Reverse Transfer Capacitance	Crss	—	47	—	pF		
Gate Resistance	R _G	—	8.5	—	Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg	_	6.0	_	nC		
Gate-Source Charge	Q _{gs}	_	0.6	—	nC	V _{GS} = -4.5V, V _{DS} = -10V, I _D = - 3A	
Gate-Drain Charge	Q _{gd}	_	1.8	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	4.0	_	ns		
Turn-On Rise Time	t _R	_	3.7	_	ns	$V_{DS} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t _{D(OFF)}	—	24.5	—	ns	$R_L = 10\Omega, R_G = 1.0\Omega, I_D = -1A$	
Turn-Off Fall Time	tF	_	9.5	_	ns		
Reverse Recovery Time	t _{RR}	_	8.3	—	ns	I _F = -1.0A, di/dt = 100A/µs	
Reverse Recovery Charge	Q _{RR}	—	2.0	—	nC	I _F = -1.0A, di/dt = 100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



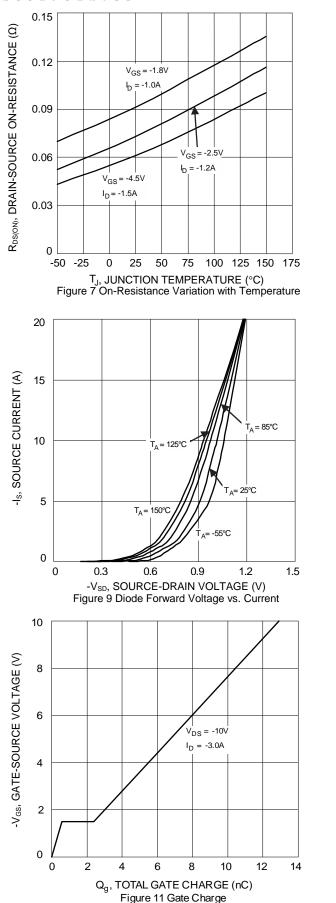
DMP2110UW

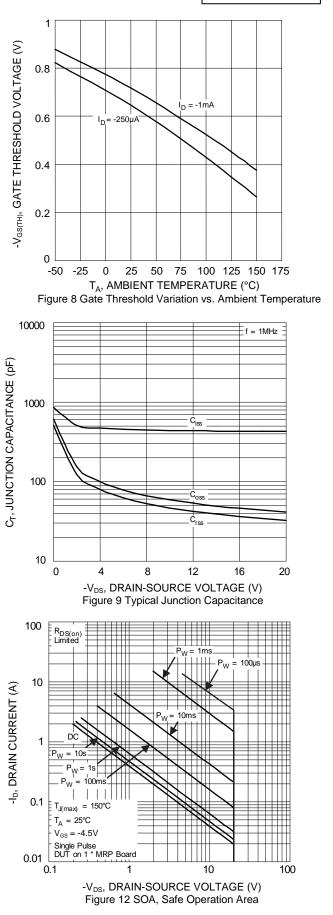




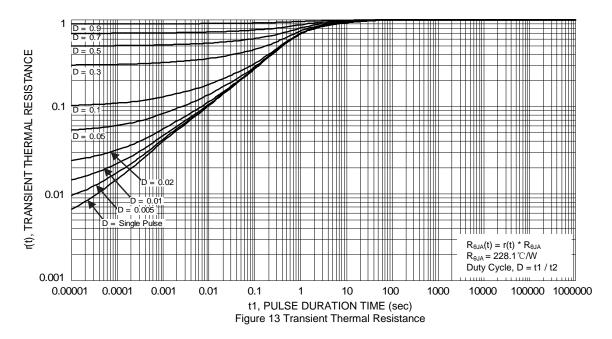










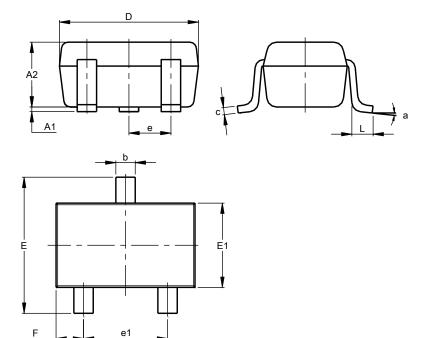




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323



SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
С	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
	All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Dimensions	Value (in mm)
C	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500

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SOT323



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